

# MC14049B, MC14050B

## Hex Buffer

The MC14049B Hex Inverter/Buffer and MC14050B Noninverting Hex Buffer are constructed with MOS P-Channel and N-Channel enhancement mode devices in a single monolithic structure. These complementary MOS devices find primary use where low power dissipation and/or high noise immunity is desired. These devices provide logic level conversion using only one supply voltage,  $V_{DD}$ .

The input-signal high level ( $V_{IH}$ ) can exceed the  $V_{DD}$  supply voltage for logic level conversions. Two TTL/DTL loads can be driven when the devices are used as a CMOS-to-TTL/DTL converter ( $V_{DD} = 5.0\text{ V}$ ,  $V_{OL} \leq 0.4\text{ V}$ ,  $I_{OL} \geq 3.2\text{ mA}$ ).

Note that pins 13 and 16 are not connected internally on these devices; consequently connections to these terminals will not affect circuit operation.

### Features

- High Source and Sink Currents
- High-to-Low Level Converter
- Supply Voltage Range = 3.0 V to 18 V
- $V_{IN}$  can exceed  $V_{DD}$
- Meets JEDEC B Specifications
- Improved ESD Protection On All Inputs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

### MAXIMUM RATINGS (Voltages Referenced to $V_{SS}$ )

Symbol	Parameter	Value	Unit
$V_{DD}$	DC Supply Voltage Range	-0.5 to +18.0	V
$V_{in}$	Input Voltage Range (DC or Transient)	-0.5 to +18.0	V
$V_{out}$	Output Voltage Range (DC or Transient)	-0.5 to $V_{DD} + 0.5$	V
$I_{in}$	Input Current (DC or Transient) per Pin	$\pm 10$	mA
$I_{out}$	Output Current (DC or Transient) per Pin	$\pm 45$	mA
$P_D$	Power Dissipation, per Package (Note 1) (Plastic) (SOIC)	825 740	mW
$T_A$	Ambient Temperature Range	-55 to +125	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature Range	-65 to +150	$^{\circ}\text{C}$
$T_L$	Lead Temperature (8-Second Soldering)	260	$^{\circ}\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: See Figure 3.

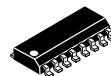
This device contains protection circuitry to protect the inputs against damage due to high static voltages or electric fields referenced to the  $V_{SS}$  pin only. Extra precautions must be taken to avoid applications of any voltage higher than the maximum rated voltages to this high-impedance circuit. For proper operation, the ranges  $V_{SS} \leq V_{in} \leq 18\text{ V}$  and  $V_{SS} \leq V_{out} \leq V_{DD}$  are recommended.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.

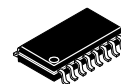


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SOIC-16  
D SUFFIX  
CASE 751B

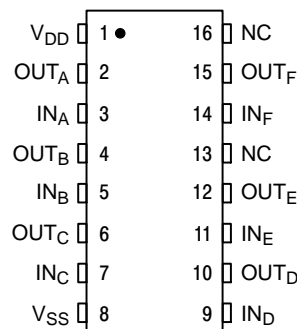


SOEIAJ-16  
F SUFFIX  
CASE 966

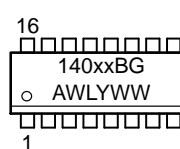


TSSOP-16  
DT SUFFIX  
CASE 948F

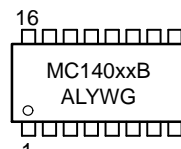
### PIN ASSIGNMENT



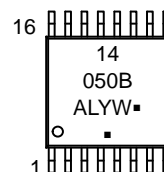
### MARKING DIAGRAMS



SOIC-16



SOEIAJ-16



TSSOP-16

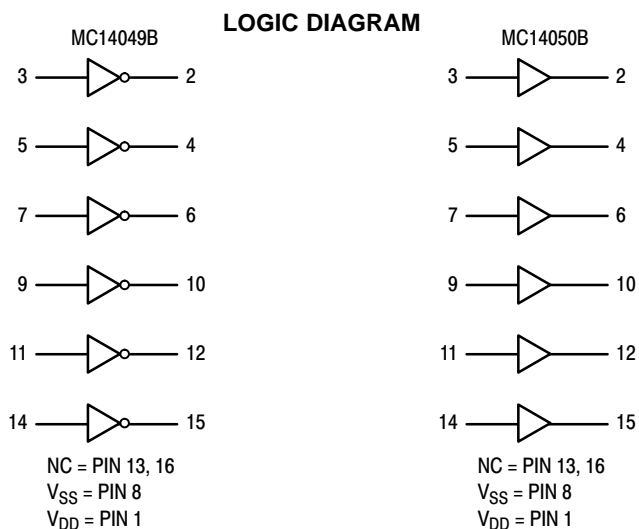
- xx = Specific Device Code
- A = Assembly Location
- WL, L = Wafer Lot
- YY, Y = Year
- WW, W = Work Week
- G or ▪ = Pb-Free Indicator

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MC14049BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14049BDR2G	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel
NLV14049BDR2G*	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel
MC14049BFELG	SOEIAJ-16 (Pb-Free)	2000 Units / Tape & Reel
MC14050BDG	SOIC-16 (Pb-Free)	48 Units / Rail
NLV14050BDG*	SOIC-16 (Pb-Free)	48 Units / Rail
MC14050BDR2G	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel
NLV14050BDR2G*	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel
MC14050BDTG	TSSOP-16 (Pb-Free)	96 Units / Rail
NLV14050BDTG*	TSSOP-16 (Pb-Free)	96 Units / Rail
MC14050BDTR2G	TSSOP-16 (Pb-Free)	2500 Units / Tape & Reel
MC14050BFELG	SOEIAJ-16 (Pb-Free)	2000 Units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

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## ELECTRICAL CHARACTERISTICS (Voltages Referenced to V<sub>SS</sub>)

Characteristic	Symbol	V <sub>DD</sub> Vdc	-55°C		+25°C			+125°C		Unit
			Min	Max	Min	Typ (Note 2)	Max	Min	Max	
Output Voltage V <sub>in</sub> = V <sub>DD</sub>  V <sub>in</sub> = 0	"0" Level  V <sub>OL</sub>	5.0	-	0.05	-	0	0.05	-	0.05	Vdc
		10	-	0.05	-	0	0.05	-	0.05	
		15	-	0.05	-	0	0.05	-	0.05	
	"1" Level  V <sub>OH</sub>	5.0	4.95	-	4.95	5.0	-	4.95	-	Vdc
		10	9.95	-	9.95	10	-	9.95	-	
		15	14.95	-	14.95	15	-	14.95	-	
Input Voltage (V <sub>O</sub> = 4.5 Vdc) (V <sub>O</sub> = 9.0 Vdc) (V <sub>O</sub> = 13.5 Vdc)  (V <sub>O</sub> = 0.5 Vdc) (V <sub>O</sub> = 1.0 Vdc) (V <sub>O</sub> = 1.5 Vdc)	"0" Level  V <sub>IL</sub>	5.0	-	1.5	-	2.25	1.5	-	1.5	Vdc
		10	-	3.0	-	4.50	3.0	-	3.0	
		15	-	4.0	-	6.75	4.0	-	4.0	
	"1" Level  V <sub>IH</sub>	5.0	3.5	-	3.5	2.75	-	3.5	-	Vdc
		10	7.0	-	7.0	5.50	-	7.0	-	
		15	11	-	11	8.25	-	11	-	
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)  (V <sub>OL</sub> = 0.4 Vdc) (V <sub>OL</sub> = 0.5 Vdc) (V <sub>OL</sub> = 1.5 Vdc)	Source  I <sub>OH</sub>	5.0	-1.6	-	-1.25	-2.5	-	-1.0	-	mAdc
		10	-1.6	-	-1.30	-2.6	-	-1.0	-	
		15	-4.7	-	-3.75	-10	-	-3.0	-	
	Sink  I <sub>OL</sub>	5.0	3.75	-	3.2	6.0	-	2.6	-	mAdc
		10	10	-	8.0	16	-	6.6	-	
		15	30	-	24	40	-	19	-	
Input Current	I <sub>in</sub>	15	-	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
Input Capacitance (V <sub>in</sub> = 0)	C <sub>in</sub>	-	-	-	-	10	20	-	-	pF
Quiescent Current (Per Package)	I <sub>DD</sub>	5.0	-	1.0	-	0.002	1.0	-	30	μAdc
		10	-	2.0	-	0.004	2.0	-	60	
		15	-	4.0	-	0.006	4.0	-	120	
Total Supply Current (Notes 3 & 4) (Dynamic plus Quiescent, per package) (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)	I <sub>T</sub>	5.0	I <sub>T</sub> = (1.8 μA/kHz) f + I <sub>DD</sub>							μAdc
		10	I <sub>T</sub> = (3.5 μA/kHz) f + I <sub>DD</sub>							
		15	I <sub>T</sub> = (5.3 μA/kHz) f + I <sub>DD</sub>							

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
3. The formulas given are for the typical characteristics only at +25°C
4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

Where: I<sub>T</sub> is in μA (per Package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency and k = 0.002.

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## AC SWITCHING CHARACTERISTICS (Note 5) ( $C_L = 50 \text{ pF}$ , $T_A = +25^\circ\text{C}$ )

Characteristic	Symbol	$V_{DD}$ Vdc	Min	Typ (Note 6)	Max	Unit
Output Rise Time $t_{TLH} = (0.7 \text{ ns/pF}) C_L + 65 \text{ ns}$ $t_{TLH} = (0.25 \text{ ns/pF}) C_L + 37.5 \text{ ns}$ $t_{TLH} = (0.2 \text{ ns/pF}) C_L + 30 \text{ ns}$	$t_{TLH}$	5.0 10 15	– – –	100 50 40	160 80 60	ns
Output Fall Time $t_{THL} = (0.2 \text{ ns/pF}) C_L + 30 \text{ ns}$ $t_{THL} = (0.06 \text{ ns/pF}) C_L + 17 \text{ ns}$ $t_{THL} = (0.04 \text{ ns/pF}) C_L + 13 \text{ ns}$	$t_{THL}$	5.0 10 15	– – –	40 20 15	60 40 30	ns
Propagation Delay Time $t_{PLH} = (0.33 \text{ ns/pF}) C_L + 63.5 \text{ ns}$ $t_{PLH} = (0.19 \text{ ns/pF}) C_L + 30.5 \text{ ns}$ $t_{PLH} = (0.06 \text{ ns/pF}) C_L + 27 \text{ ns}$	$t_{PLH}$	5.0 10 15	– – –	80 40 30	140 80 60	ns
Propagation Delay Time $t_{PHL} = (0.2 \text{ ns/pF}) C_L + 30 \text{ ns}$ $t_{PHL} = (0.1 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{PHL} = (0.05 \text{ ns/pF}) C_L + 12.5 \text{ ns}$	$t_{PHL}$	5.0 10 15	– – –	40 20 15	80 40 30	ns

5. The formulas given are for the typical characteristics only at  $25^\circ\text{C}$ .

6. Data labeled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

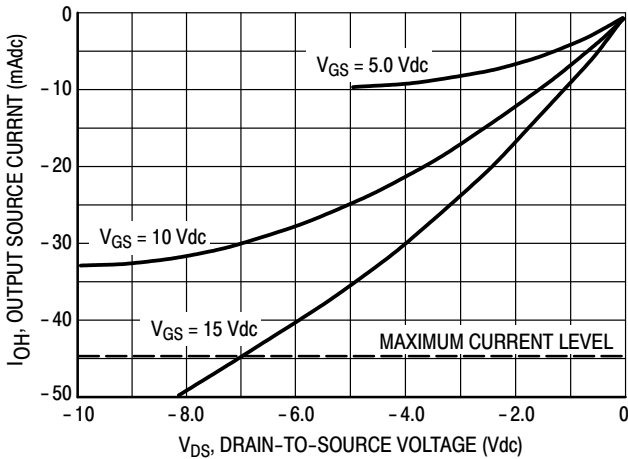
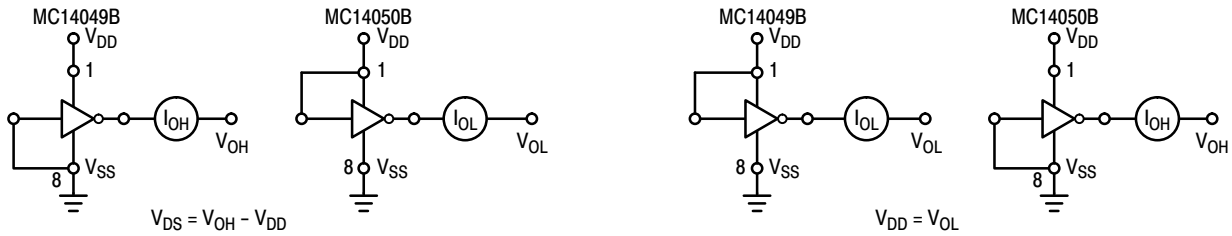


Figure 1. Typical Output Source Characteristics

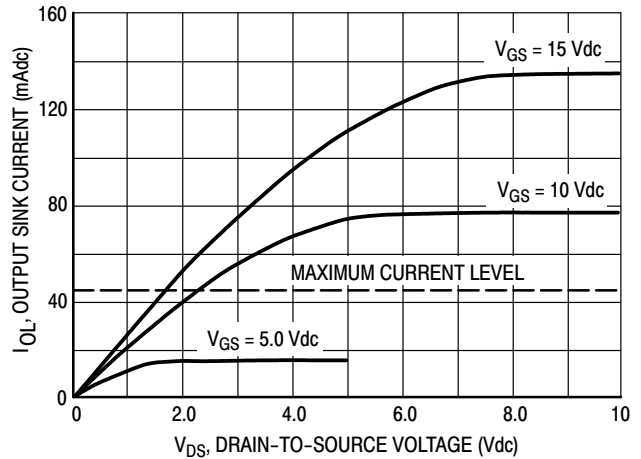


Figure 2. Typical Output Sink Characteristics

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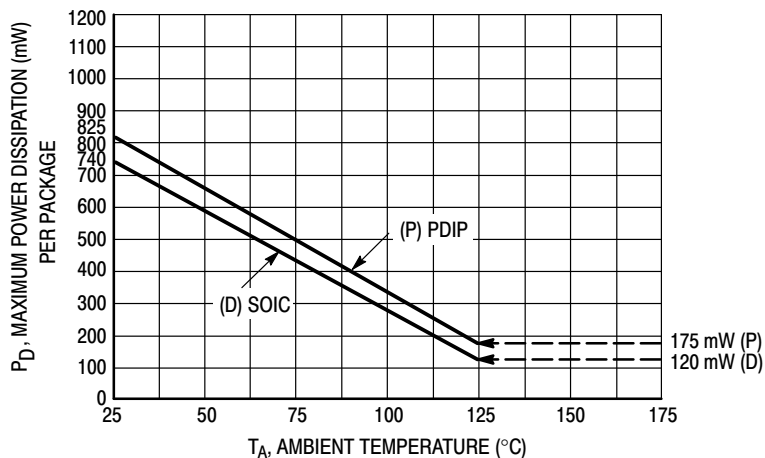


Figure 3. Ambient Temperature Power Derating

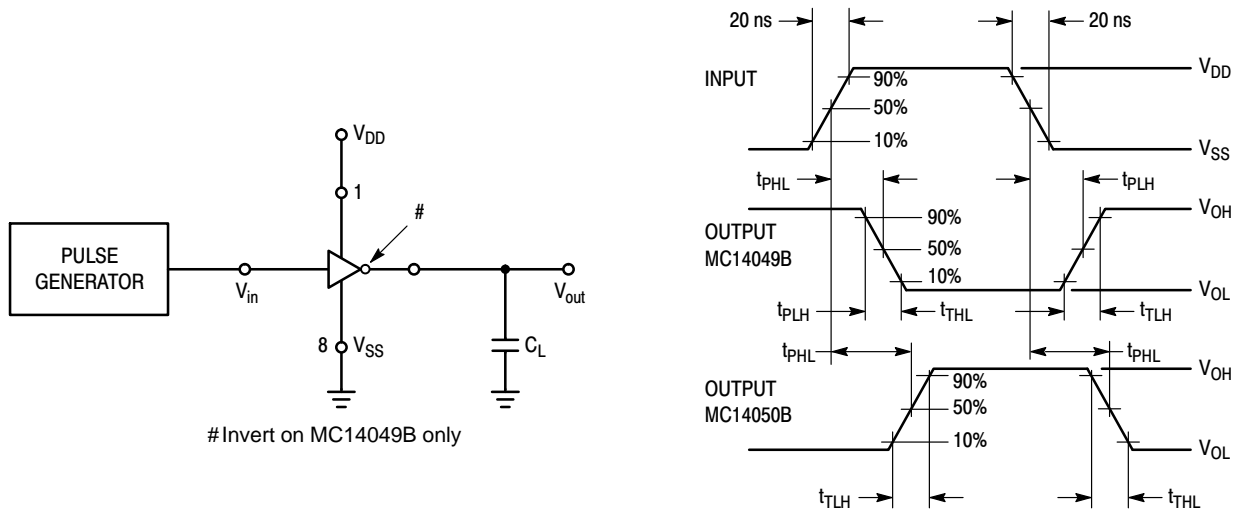
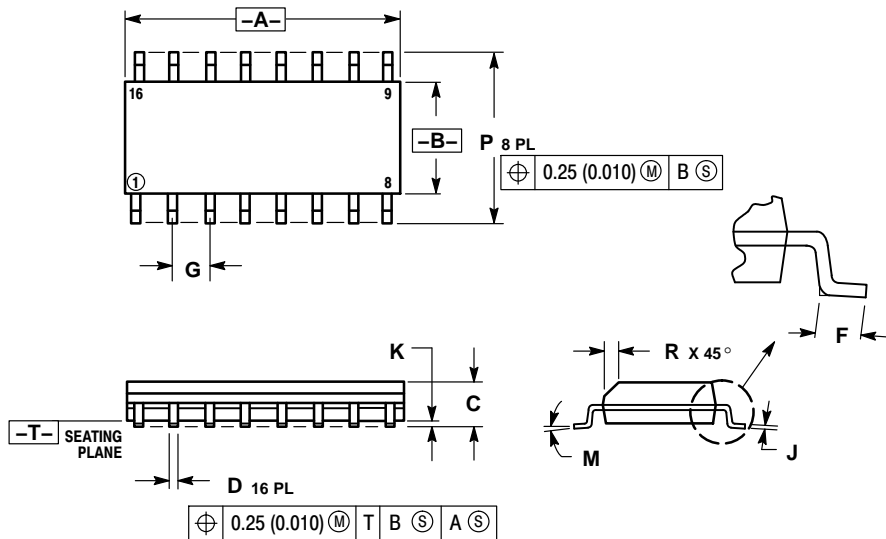


Figure 4. Switching Time Test Circuit and Waveforms

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## PACKAGE DIMENSIONS

SOIC-16  
D SUFFIX  
CASE 751B-05  
ISSUE K

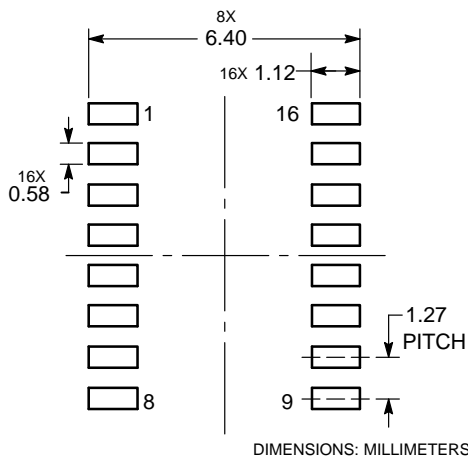


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0° - 7°		0° - 7°	
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

### SOLDERING FOOTPRINT\*



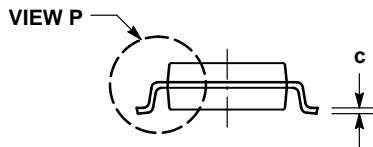
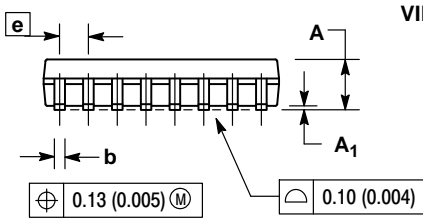
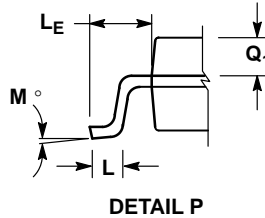
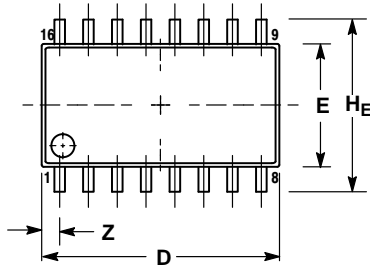
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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## PACKAGE DIMENSIONS


SOEIAJ-16  
F SUFFIX  
CASE 966  
ISSUE A



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H <sub>E</sub>	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L <sub>E</sub>	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

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